

## **VB927T**

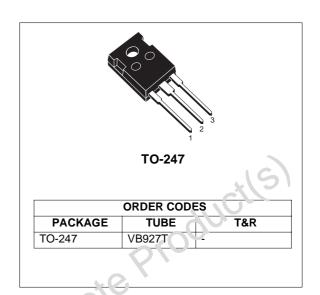
# HIGH VOLTAGE IGNITION COIL DRIVER POWER I.C.

TYPE	V <sub>cl</sub>	I <sub>cl</sub>	V <sub>cg(sat)</sub>
VB927T	380V	9.5A	2.5V

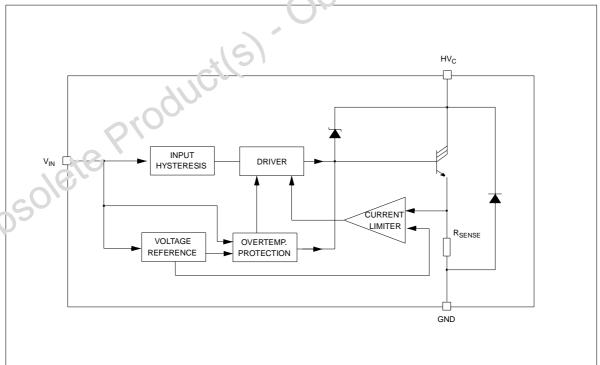
- NO EXTERNAL COMPONENT REQUIRED
- COIL CURRENT LIMIT INTERNALLY SET
- INTEGRATED HIGH VOLTAGE CLAMP
- HIGH RUGGEDNESS
- OVERTEMPERATURE PROTECTION

#### **DESCRIPTION**

The VB927T is a monolithic high voltage integrated circuit made by using the STMicroelectronics VIPower™ technology, which combines vertical current flow power trilinton with a coil current and a collector voltage clamping. The device is particularly suitable for application in high performance electronic car ignition, where coil current limitation and voltage clamping are required.



#### **BLOCK DIAGRAM**

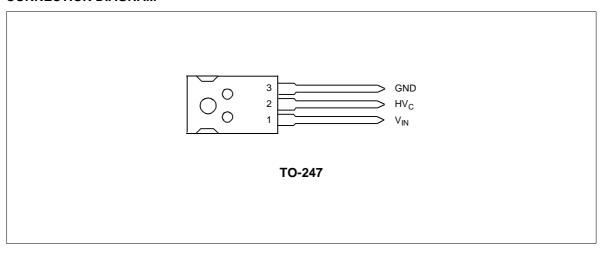


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## **ABSOLUTE MAXIMUM RATING**

Symbol	Parameter	Value	Unit	
HV <sub>c</sub>	Collector Voltage	Internally limited	V	
V <sub>IN</sub>	Maximum Input Voltage	15		
I <sub>C</sub>	Collector Current	Internally limited	Α	
I <sub>IN</sub>	Input Current	Internally limited	mA	
P <sub>tot</sub>	Total Dissipation At T <sub>c</sub> =25°c	150	W	
T <sub>stg</sub>	Storage Temperature	-40 to 150	°C	
Ti	Junction Operating Temperature	-40 to 150	°C	

## **CONNECTION DIAGRAM**





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#### THERMAL DATA

Symbol	Parameter		Value	Unit
R <sub>thj-case</sub>	Thermal Resistance Junction-case	(MAX)	0.6	°C/W
R <sub>thi-amb</sub>	Thermal Resistance Junction-ambient	(MAX)	30	°C/W

# $\textbf{ELECTRICAL CHARACTERISTICS} \ (\text{V}_{\text{CC}} = 14 \text{V}; \ -40 \text{V} < \text{T}_{j} < 125 ^{\circ}\text{C} \ \text{unless otherwise specified})$

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
I <sub>leak</sub>	Collector Cut-off Current	V <sub>IN</sub> =0V; HV <sub>C</sub> =250V			250	μΑ
V <sub>cl</sub> (*)	Clamping Voltage	-40°C < T <sub>j</sub> < 125°C	380	420	490	V
V	Power Stage Saturation	$I_C=5A$ ; $I_{1N}=10mA$ ; $25^{\circ}C \le T_j \le 125^{\circ}C$			2.5	V
$V_{cg(sat)}$	Voltage	$I_C=6A; I_{IN}=10mA; -40^{\circ}C \le T_j \le 25^{\circ}C$			3	V
I <sub>cl</sub> (*)	Coil Current Limit	$V_{IN}=5V; -40^{\circ}C \le T_{j} \le 125^{\circ}C$	8.5		9.5	Α
	Input Current	V <sub>IN</sub> =5V; I <sub>C</sub> =5A			10	mA
I <sub>IN</sub>		V <sub>IN</sub> =5V; I <sub>C</sub> =5A; T <sub>j</sub> =25°C	3		10	mA
V <sub>f</sub> (**)	Diode Forward Voltage	I <sub>f</sub> =10A; T <sub>j</sub> =25°C	1.2	2.2	3.2	V
V <sub>INH</sub>	Input Voltage (ON)	On state input threshold	3.2		3.6	V
V <sub>INL</sub>	Input Voltage (OFF)	Off state input threshold	3		3.4	V
V <sub>IN(hyst)</sub>	Input Voltage (Hyst.)		0.2		0.6	V
t <sub>d(off)</sub>	Turn-off Time	I <sub>C</sub> =5A		30		μs
Tj	Junction Temperature Limit	See note 1	150			°C

<sup>(\*)</sup> Coil data: primary resistance  $\rm R_{C}{=}0.4$  -  $\rm 0.8\Omega;$  primary inductance  $\rm L_{C}{=}$  6 - 8 mH

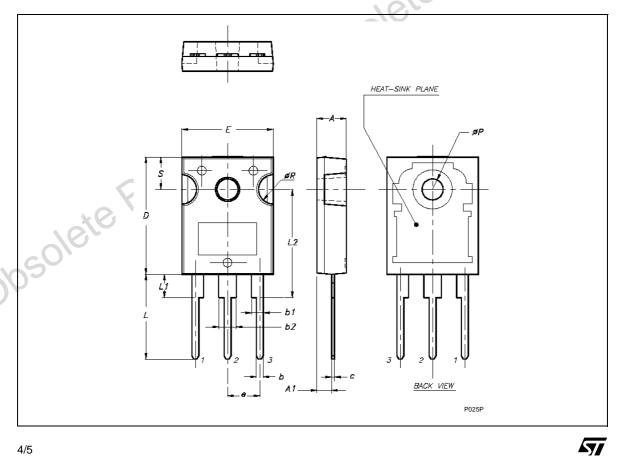


<sup>(\*\*)</sup> Pulsed: Pulse duration =300 $\mu$ s, duty cycle 1.5%

Note 1:  $T_{jmin}$ =150°C means that the behavior of the device will not be affected for junction temperature lower than 150°C. For higher temperature, the thermal protection circuit will begin its action reducing the  $I_{cl}$  limit according with the power dissipation. Chip temperature is a function of the  $R_{th}$  of the whole system in which the device will be operating.

## **TO-247 MECHANICAL DATA**

DIM	mm.			
DIM.	MIN.	TYP	MAX.	
А	4.85		5.15	
A1	2.20		2.60	
b	1.0		1.40	
b1	2.0		2.40	
b2	3.0		3.40	
С	0.40		0.80	
D	19.85		20.15	
Е	15.45		15.75	
е		5.45		
L	14.20		14.80	
L1	3.70	4.30		
L2		18.50	1,10	
ØP	3.55		3.65	
ØR	4.50		5.50	
S		5.50		
Package Weight	Gr. 4.43			



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